

BC337/338



1. Collector 2. Base 3. Emitter

Switching and Amplifier Applications

- Suitable for AF-Driver stages and low power output stages
- Complement to BC327/BC328

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CES}	Collector-Emitter Voltage : BC337 : BC338	 50 30	 V V
V_{CEO}	Collector-Emitter Voltage : BC337 : BC338	 45 25	 V V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current (DC)	800	mA
P_C	Collector Power Dissipation	625	mW
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

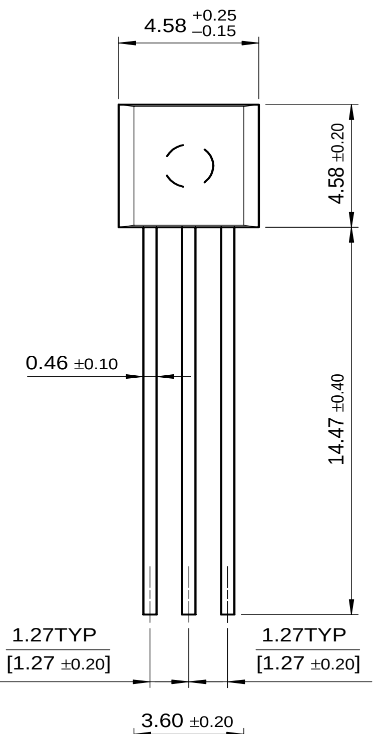
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CEO}	Collector-Emitter Breakdown Voltage : BC337 : BC338	I_C=10mA, I_B=0	 45 25			 V V
BV_{CES}	Collector-Emitter Breakdown Voltage : BC337 : BC338	I_C=0.1mA, V_{BE}=0	 50 30			 V V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E=0.1mA, I_C=0	5			V
I_{CES}	Collector Cut-off Current : BC337 : BC338	 V_{CE}=45V, I_B=0 V_{CE}=25V, I_B=0		 2 2	 100 100	 nA nA
h_{FE1} h_{FE2}	DC Current Gain	V_{CE}=1V, I_C=100mA V_{CE}=1V, I_C=300mA	100 60		630	
V_{CE} (sat)	Collector-Emitter Saturation Voltage	I_C=500mA, I_B=50mA			0.7	V
V_{BE} (on)	Base Emitter On Voltage	V_{CE}=1V, I_C=300mA			1.2	V
f_T	Current Gain Bandwidth Product	V_{CE}=5V, I_C=10mA, f=50MHz		100		MHz
C_{ob}	Output Capacitance	V_{CB}=10V, I_E=0, f=1MHz		12		pF

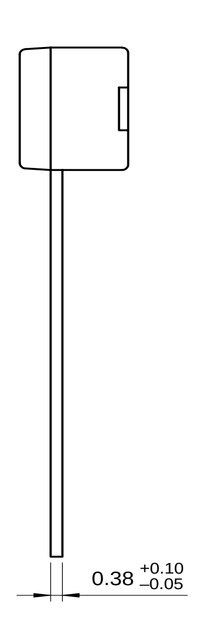
h_{FE} Classification

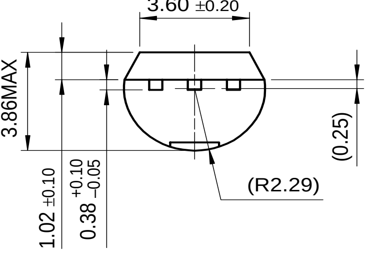
Classification	16	25	40
h_{FE1}	100 ~ 250	160 ~ 400	250 ~ 630
h_{FE2}	60-	100-	170-

Package Dimensions

TO-92







Dimensions in Millimeters

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